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April 1st, 2010 Renesas Electronics Corporation

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NP110N04PDG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP110N04PDG is N-channel MOS Field Effect Transistor designed for high current switching applications.

<R> ORDERING INFORMATION

| PART NUMBER | LEAD PLATING | PACKING | PACKAGE |
|------------------------|---------------|------------|------------------|
| NP110N04PDG-E1-AZ Note | Pure Sn (Tin) | Tape | TO-263 (MP-25ZP) |
| NP110N04PDG-E2-AZ Note | | 800 p/reel | typ. 1.5 g |

Note See "TAPE INFORMATION"

FEATURES

• Channel temperature 175 degree rating

• Super low on-state resistance

 $R_{DS(on)1} = 1.8 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, ID} = 55 \text{ A)}$

 $R_{DS(on)2} = 3.2 \, m\Omega$ MAX. (Vgs = 4.5 V, ID = 55 A)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Drain to Source Voltage (Vgs = 0 V) | VDSS | 40 | V |
|---|--------------------|-------------|----|
| Gate to Source Voltage (Vps = 0 V) | Vgss | ±20 | V |
| Drain Current (DC) (Tc = 25°C) | I _{D(DC)} | ±110 | Α |
| Drain Current (pulse) Note1 | ID(pulse) | ±440 | Α |
| Total Power Dissipation (T _A = 25°C) | P _{T1} | 1.8 | W |
| Total Power Dissipation (Tc = 25°C) | P _{T2} | 288 | W |
| Channel Temperature | Tch | 175 | °C |
| Storage Temperature | Tstg | -55 to +175 | °C |
| Repetitive Avalanche Current Note2 | lar | 72 | Α |
| Repetitive Avalanche Energy Note2 | Ear | 518 | mJ |

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Tch \leq 150°C, VDD = 20 V, Rg = 25 Ω , Vgs = 20 \rightarrow 0 V

THERMAL RESISTANCE

| Channel to Case Thermal Resistance | Rth(ch-C) | 0.52 | °C/W |
|---------------------------------------|-----------|------|------|
| Channel to Ambient Thermal Resistance | Rth(ch-A) | 83.3 | °C/W |

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(TO-263)





ELECTRICAL CHARACTERISTICS (TA = 25°C)

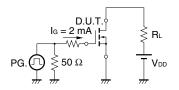
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|----------------------|---|------|-------|-------|------|
| Zero Gate Voltage Drain Current | IDSS | V _{DS} = 40 V, V _{GS} = 0 V | | | 1 | μΑ |
| Gate Leakage Current | Igss | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ | | | ±100 | nA |
| Gate to Source Threshold Voltage Note | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \mu\text{A}$ | 1.5 | 2.0 | 2.5 | > |
| Forward Transfer Admittance Note | y _{fs} | V _{DS} = 10 V, I _D = 55 A | 45 | 89 | | S |
| Drain to Source On-state Resistance Note | R _{DS(on)1} | Vgs = 10 V, ID = 55 A | | 1.4 | 1.8 | mΩ |
| | RDS(on)2 | V _{GS} = 4.5 V, I _D = 55 A | | 2.1 | 3.2 | mΩ |
| Input Capacitance | Ciss | V _{DS} = 25 V | | 14500 | 25700 | pF |
| Output Capacitance | Coss | Vgs = 0 V | | 1360 | 2130 | pF |
| Reverse Transfer Capacitance | Crss | f = 1 MHz | | 810 | 1610 | pF |
| Turn-on Delay Time | td(on) | V _{DD} = 20 V, I _D = 55 A | | 46 | 120 | ns |
| Rise Time | tr | Vgs = 10 V | | 124 | 350 | ns |
| Turn-off Delay Time | td(off) | $R_G = 0 \Omega$ | | 122 | 260 | ns |
| Fall Time | tf | | | 19 | 60 | ns |
| Total Gate Charge | Q _G | VDD = 32 V | | 230 | 390 | nC |
| Gate to Source Charge | Q _{GS} | Vgs = 10 V | | 42 | | nC |
| Gate to Drain Charge | Q _{GD} | lo = 110 A | | 75 | | nC |
| Body Diode Forward Voltage Note | V _F (S-D) | IF = 110 A, Vgs = 0 V | | 0.9 | 1.5 | V |
| Reverse Recovery Time | trr | IF = 110 A, VGS = 0 V | | 55 | | ns |
| Reverse Recovery Charge | Qrr | di/dt = 100 A/μs | | 72 | | nC |

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

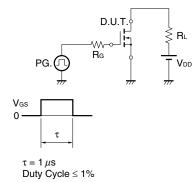
$V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DS} V_{DS} V_{DS} V_{DS}

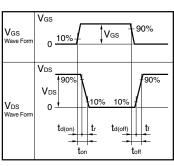




Starting Tch

TEST CIRCUIT 2 SWITCHING TIME

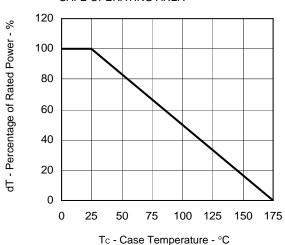




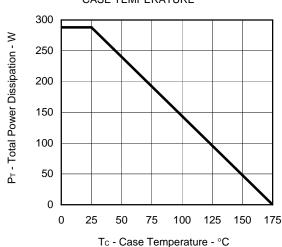
<R>

TYPICAL CHARACTERISTICS (TA = 25°C)

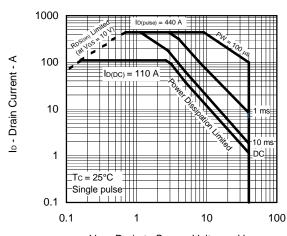
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

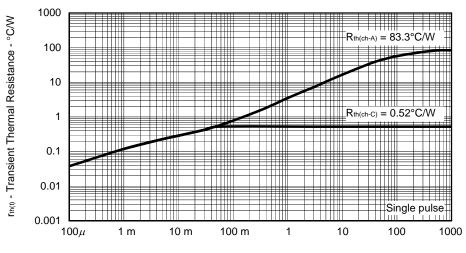


FORWARD BIAS SAFE OPERATING AREA



 $V_{\text{\scriptsize DS}}$ - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



PW - Pulse Width - s

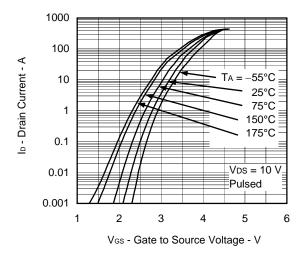
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE 500 VGS = 10 V 4.5 V Pulsed

0.4

0.2

0

FORWARD TRANSFER CHARACTERISTICS

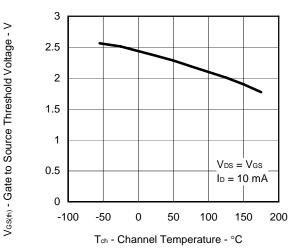


GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

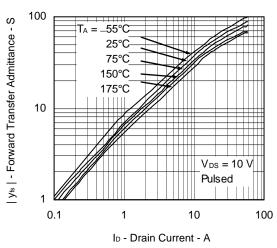
V_{DS} - Drain to Source Voltage - V

0.6

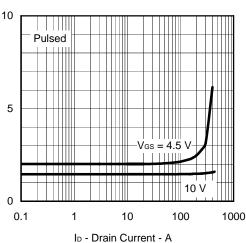
8.0



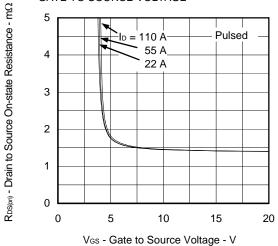
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



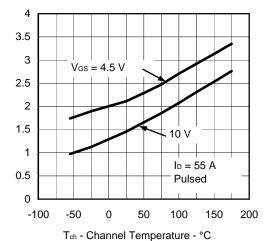
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



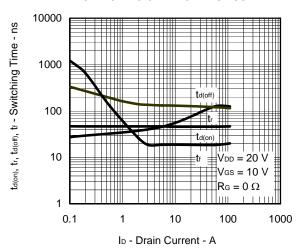
Ros(on) - Drain to Source On-state Resistance - mΩ

R_{DS(o1)} - Drain to Source On-state Resistance - mΩ

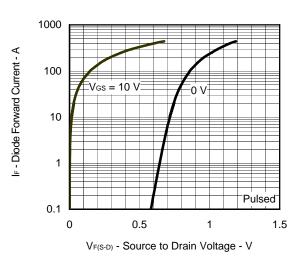




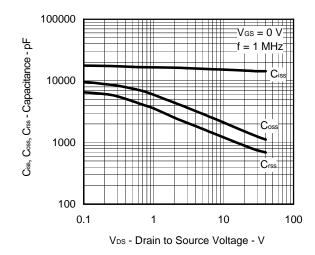
SWITCHING CHARACTERISTICS



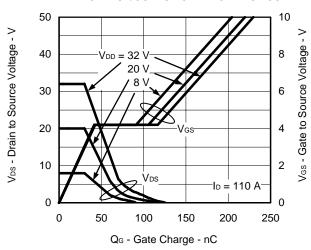
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



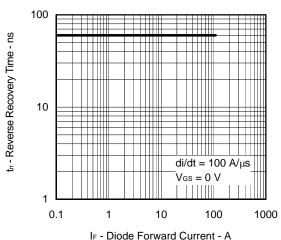
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

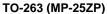


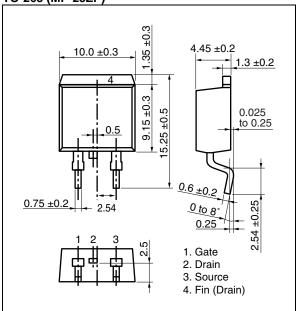
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



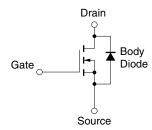


PACKAGE DRAWING (Unit: mm)





EQUIVALENT CIRCUIT



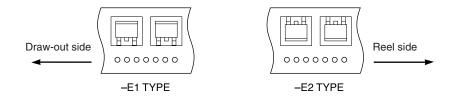
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

6

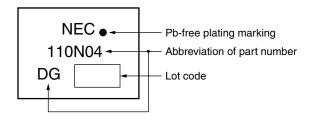


<R> TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



<R> MARKING INFORMATION



<R>> RECOMMENDED SOLDERING CONDITIONS

The NP110N04PDG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

| Soldering Method | Soldering Conditions | Recommended Condition Symbol |
|------------------|--|------------------------------|
| Infrared reflow | Maximum temperature (Package's surface temperature): 260°C or below | IR60-00-3 |
| | Time at maximum temperature: 10 seconds or less | |
| | Time of temperature higher than 220°C: 60 seconds or less | |
| | Preheating time at 160 to 180°C: 60 to 120 seconds | |
| | Maximum number of reflow processes: 3 times | |
| | Maximum chlorine content of rosin flux (percentage mass): 0.2% or less | |
| Partial heating | Maximum temperature (Pin temperature): 350°C or below | P350 |
| | Time (per side of the device): 3 seconds or less | |
| | Maximum chlorine content of rosin flux: 0.2% (wt.) or less | |

Caution Do not use different soldering methods together (except for partial heating).

Data Sheet D17561EJ2V0DS 7

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